NSN 5962-01-370-2012

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Features Provided:
Burn in and programmed
Inclosure Material:
Ceramic
Inclosure Configuration:
Flat pack
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
7.0 volts power source
Memory Device Type:
Pal
Terminal Type And Quantity:
24 flat leads
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A458a0